TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2776

Chopper Regulator, DC-DC Converter and Motor Drive Applications

• Low drain-source ON-resistance : $R_{DS (ON)} = 0.75 \Omega (typ.)$ • High forward transfer admittance : $|Y_{fs}| = 7.0 S (typ.)$

• Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 500 V)

• Enhancement mode : V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	500	(V)	
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	500	(/ y / 5)	
Gate-source voltage		V_{GSS}	±30	\bigvee	
Drain current	DC (Note 1)	ΙD	8	A	
	Pulse (Note 1)	I_{DP}	32	> A	
Drain power dissipation (Tc = 25°C)		P_{D}	65	W	
Single pulse avalanche energy (Note 2)		EAS	312	mJ	
Avalanche current		I _{AR}	8	<< <u>A</u>	
Repetitive avalanche energy (Note 3)		EAR	6.5	mJ	
Channel temperature		Teh	150	°C	
Storage temperature range		((T _{stg}	-55 to 150	//°c	

Note: Using continuously under heavy toads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions") Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate; etc).

Thermal Characteristics

Characteristics Symbol	Max	Unit
Thermal resistance, channel to case Rth (ch-c)	1.92	°C/W
Thermal resistance, channel to ambient Rth (ch-a)	83.3	°C/W

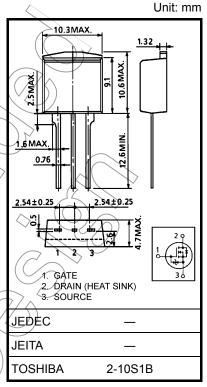
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 8.3 mH, R_G = 25 Ω ,

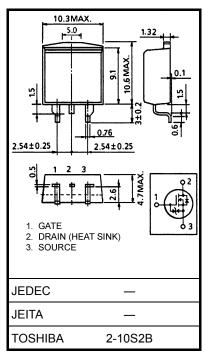
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



Weight: 1.5 g (typ.)



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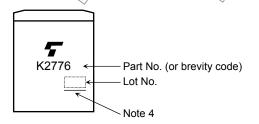
Electrical Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±25 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cur	rrent	I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	\ <u></u>	_	100	μA
Drain-source br	eakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	500		_	V
Gate threshold v	oltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) >_	4.0	V
Drain-source Ol	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 4 A	<u> </u>	0.75	0.85	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 4 A	3.5	7.0	_	S
Input capacitano	е	C _{iss}		_	1300	_	
Reverse transfe	r capacitance	C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	130	_	pF
Output capacita	nce	Coss		_	400	_	
Switching time	Rise time	t _r	V _{GS} OV I ID=4A VOUT	- (26	>	
	Turn-on time	t _{on}	R _L =50Ω		45) _	
	Fall time	t _f		7()	40	_	ns
	Turn-off time	t _{off}	$V_{DD} = 200V$ Duty $\leq 1\%$, $t_{W} = 10 \mu s$) -	140	_	
Total gate charg plus gate-drain)		Qg		_	30	_	
Gate-source ch	arge	Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, V_{D} = 8 \text{ A}$	_	17	_	nC
Gate-drain ("mil	ler") Charge	Q _{gd}		_	13	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	1 _{DR}	_	_	_	8	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	32	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 8 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	Inn = 8 A Vec = 0 V dlan / dt = 100 A / us	ı	1200	-	ns
Reverse recovery charge	Q _{rr}	I _{DR} = 8 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs		10		μC

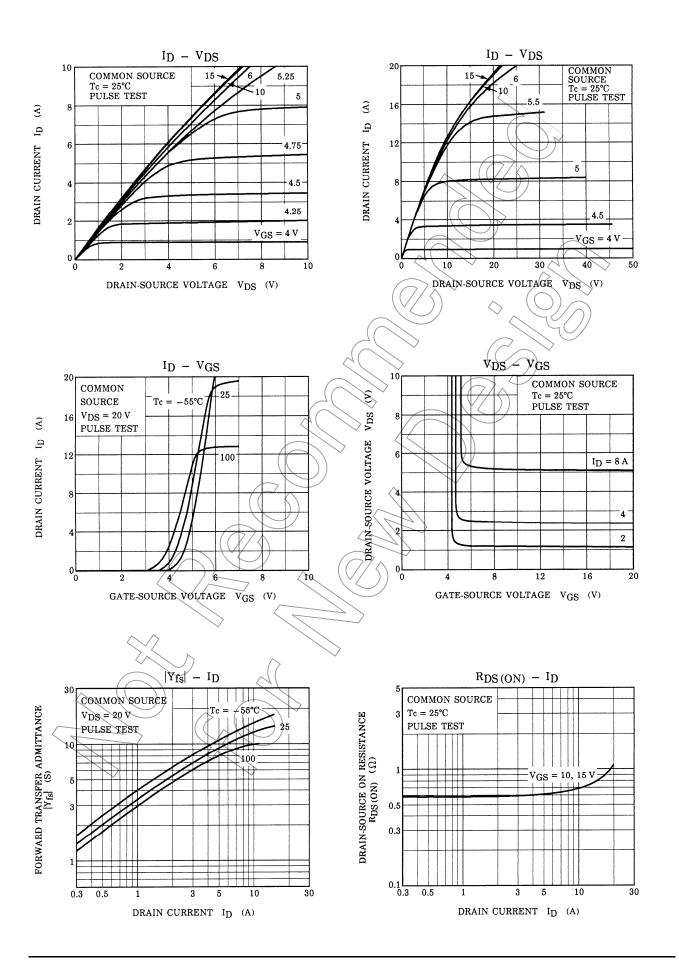




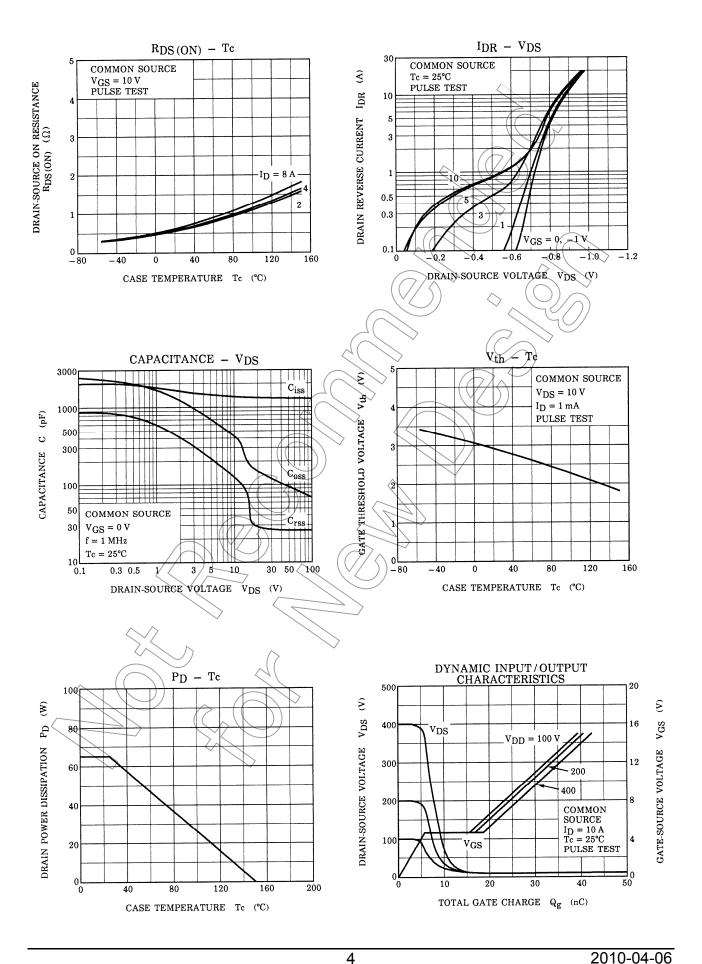
Note 4: A line under a Lot No. identifies the indication of product Labels.

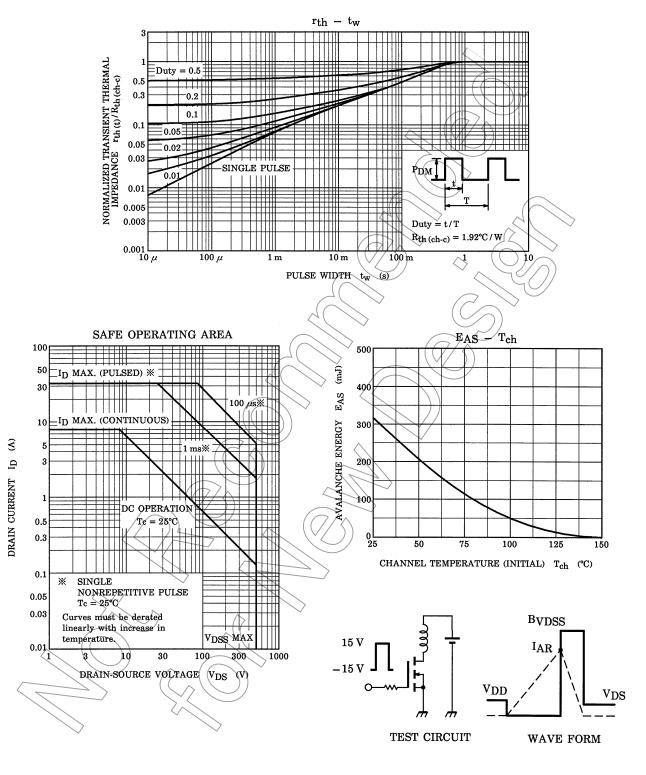
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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$$R_G = 25 \Omega$$

 $V_{DD} = 90 \text{ V, L} = 8.3 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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